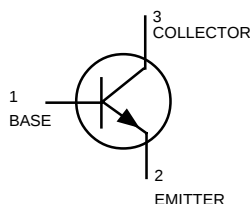


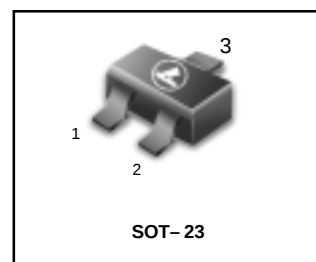
General Purpose Transistors

NPN Silicon

- Pb-Free Package is Available.



L2SC2412K*LT1



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	50	V
Collector-Base Voltage	V_{CBO}	60	V
Emitter-Base Voltage	V_{EBO}	7.0	V
Collector Current — Continuous	I_C	150	mA
Collector power dissipation	P_C	0.2	W
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 ~ +150	°C

DEVICE MARKING

L2SC2412KQLT1 =BQ L2SC2412KRLT1 =BR L2SC2412KSLT1 =G1F

ORDERING INFORMATION

Device	Marking	Shipping
L2SC2412KQLT1	BQ	3000 Tape & Reel
L2SC2412KQLT1G	BQ(Pb-Free)	3000 Tape & Reel
L2SC2412KRLT1	BR	3000 Tape & Reel
L2SC2412KRLT1G	BR(Pb-Free)	3000 Tape & Reel
L2SC2412KSLT1	G1F	3000 Tape & Reel
L2SC2412KSLT1G	G1F(Pb-Free)	3000 Tape & Reel

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Collector-Emitter Breakdown Voltage ($I_C = 1\text{ mA}$)	$V_{(BR)CEO}$	50	—	—	V
Emitter-Base Breakdown Voltage ($I_E = 50\text{ }\mu\text{A}$)	$V_{(BR)EBO}$	7	—	—	V
Collector-Base Breakdown Voltage ($I_C = 50\text{ }\mu\text{A}$)	$V_{(BR)CBO}$	60	—	—	V
Collector Cutoff Current ($V_{CB} = 60\text{ V}$)	I_{CBO}	—	—	0.1	μA
Emitter cutoff current ($V_{EB} = 7\text{ V}$)	I_{EBO}	—	—	0.1	μA
Collector-emitter saturation voltage ($I_C / I_B = 50\text{ mA} / 5\text{ mA}$)	$V_{CE(sat)}$	—	—	0.4	V
DC current transfer ratio ($V_{CE} = 6\text{ V}, I_C = 1\text{ mA}$)	h_{FE}	120	—	560	—
Transition frequency ($V_{CE} = 12\text{ V}, I_E = -2\text{ mA}, f = 30\text{ MHz}$)	f_T	—	180	—	MHz
Output capacitance ($V_{CB} = 12\text{ V}, I_E = 0\text{ A}, f = 1\text{ MHz}$)	C_{ob}	—	2.0	3.5	pF

h_{FE} values are classified as follows:

*	Q	R	S
h_{FE}	120~270	180~390	270~560

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Fig.1 Grounded emitter propagation characteristics

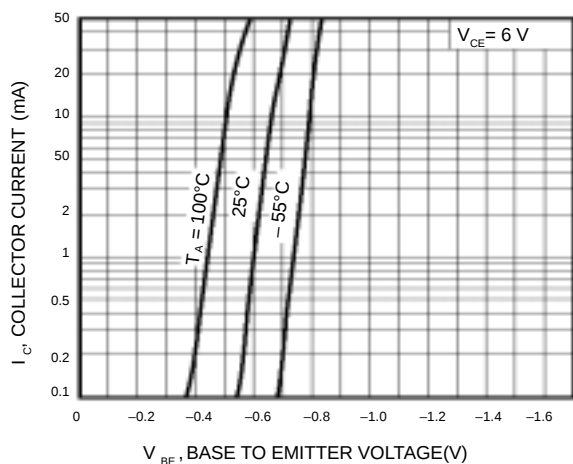


Fig.2 Grounded emitter output characteristics(I)

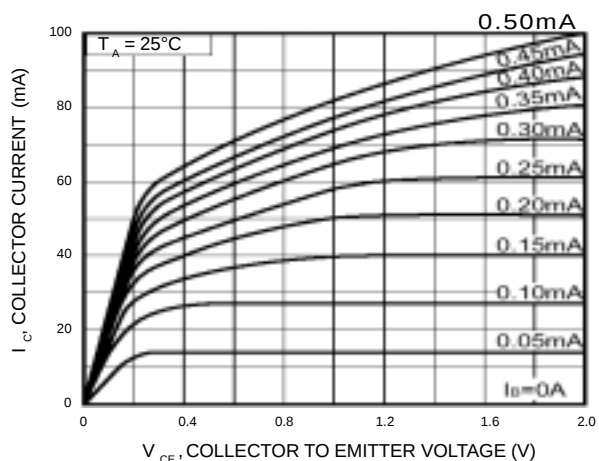


Fig.3 Grounded emitter output characteristics(II)

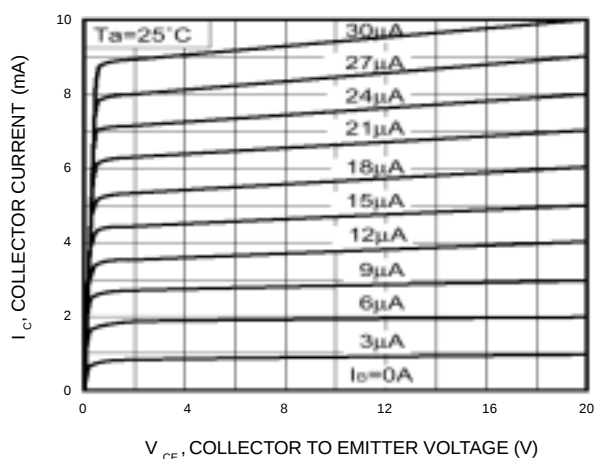


Fig.4 DC current gain vs. collector current (I)

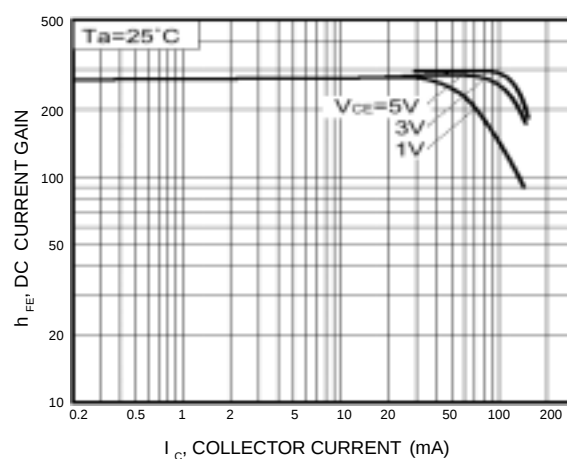


Fig.5 DC current gain vs. collector current (II)

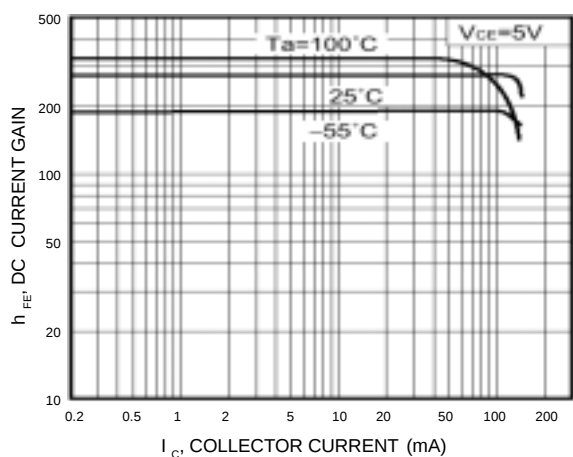
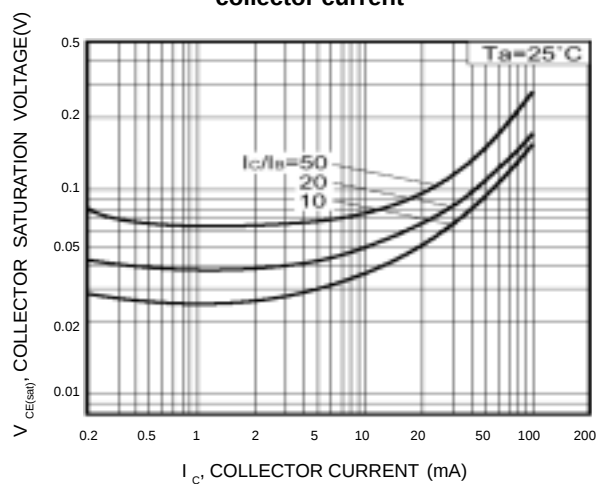


Fig.6 Collector-emitter saturation voltage vs. collector current



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Fig.7 Collector-emitter saturation voltage vs. collector current (I)

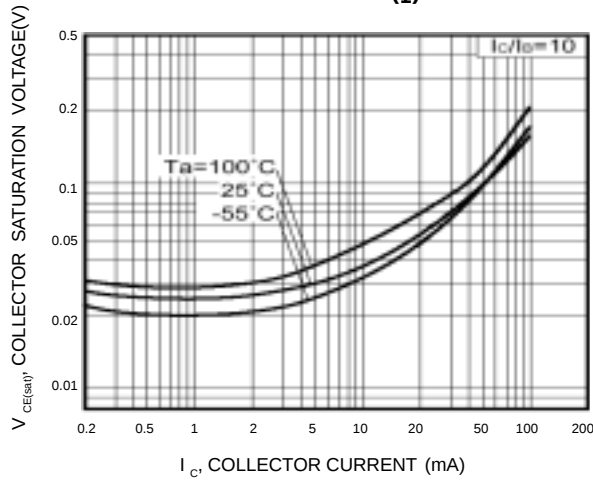


Fig.8 Collector-emitter saturation voltage vs. collector current (II)

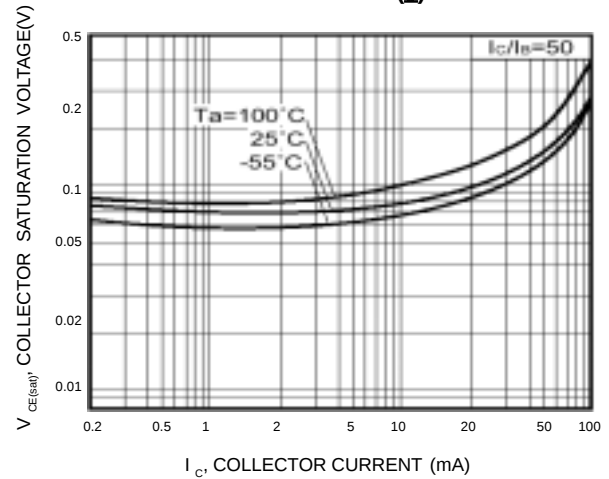
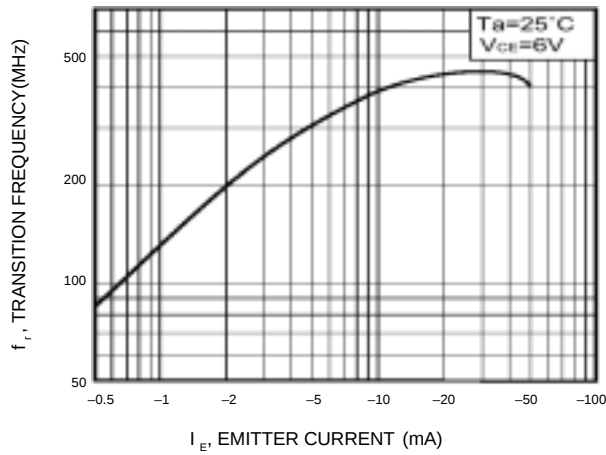


Fig.9 Gain bandwidth product vs. emitter current



**Fig.10 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage**

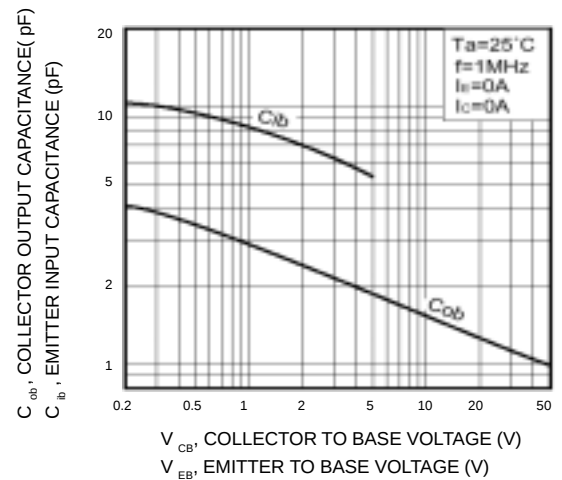


Fig.11 Base-collector time constant vs. emitter current

